

**100V PNP MEDIUM POWER TRANSISTOR IN SOT223**

**Features and Benefits**

- $BV_{CEO} > -100V$
- $I_C = -5A$  Continuous Collector Current
- Low Saturation Voltage (-90mV max @-1A)
- $R_{SAT} = 60m\Omega$  for a low equivalent On-Resistance
- $h_{FE}$  specified up to -10A for a high gain hold up
- **Lead-Free Finish; RoHS compliant (Note 1)**
- **Halogen and Antimony Free. "Green" Device (Note 2)**
- **Qualified to AEC-Q101 Standards for High Reliability**

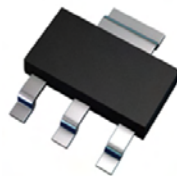
**Applications**

- Motor driving
- Line switching
- High side switches
- Subscriber line interface cards (SLIC)

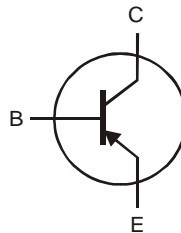
**Mechanical Data**

- Case: SOT223
- Case material: Molded Plastic. "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish annealed over Copper leadframe
- Weight: 0.112 grams (Approximate)

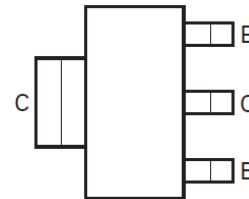
SOT223



Top View



Device Symbol



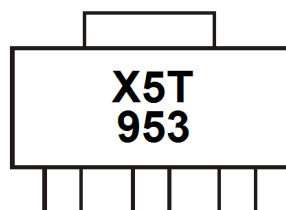
Top View  
Pin-Out

**Ordering Information (Note 3 & 4)**

Product	Grade	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZX5T953GTA	Commercial	X5T953	7	12	1,000
ZX5T953GQTA	Automotive	X5T953	7	12	1,000

- Notes:
1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
  2. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
  3. For packaging details, go to our website at <http://www.diodes.com>.
  4. Products with Q-suffix are automotive grade. Automotive products are electrical and thermal the same as the commercial, except where specified.

**Marking Information**



X5T953 = Product type Marking Code

**Maximum Ratings** @T<sub>A</sub> = 25°C unless otherwise specified

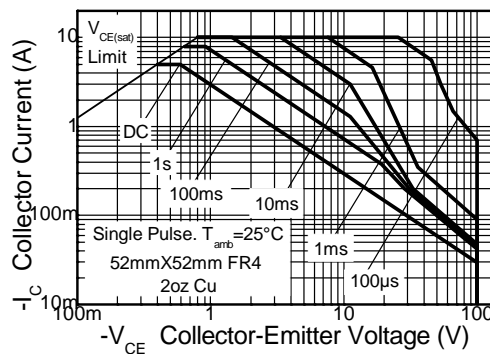
Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CB0</sub>	-140	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-100	V
Emitter-Base Voltage	V <sub>EBO</sub>	-7	V
Continuous Collector Current (Note 5)	I <sub>C</sub>	-5	A
Peak Pulse Current	I <sub>CM</sub>	-10	A

**Thermal Characteristics** @T<sub>A</sub> = 25°C unless otherwise specified

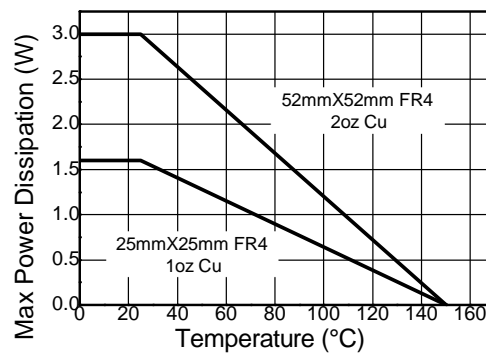
Characteristic	Symbol	Value	Unit
Power Dissipation Linear derating factor	P <sub>D</sub>	3.0	W
		24	
Thermal Resistance, Junction to Ambient	R <sub>θJA</sub>	42	°C/W
	R <sub>θJA</sub>	78	
Thermal Resistance Junction to Lead	R <sub>θJL</sub>	10.48	°C
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

- Notes:
- For a device surface mounted on 52mm x 52mm x 1.6mm FR4 PCB with high coverage of single sided 2oz copper, in still air conditions; the device is measured when operating in a steady-state condition.
  - Same as note (5), except the device is surface mounted on 25mm x 25mm with 1oz copper.
  - Thermal resistance from junction to solder-point (at the end of the collector lead).

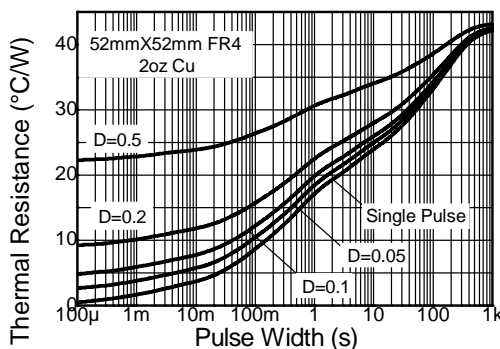
**Typical Thermal Characteristics**



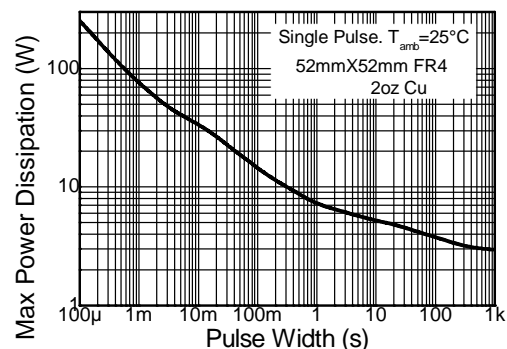
**Safe Operating Area**



**Derating Curve**



**Transient Thermal Impedance**



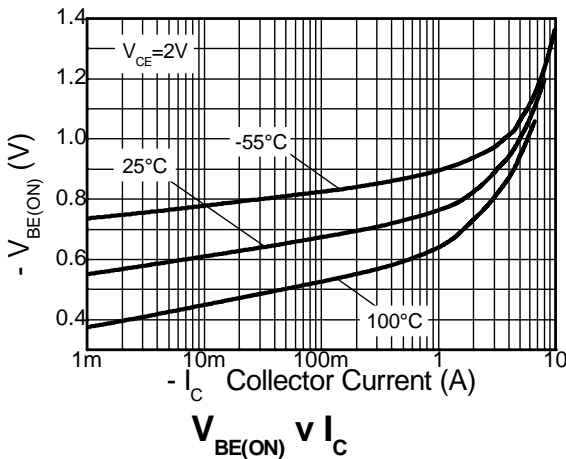
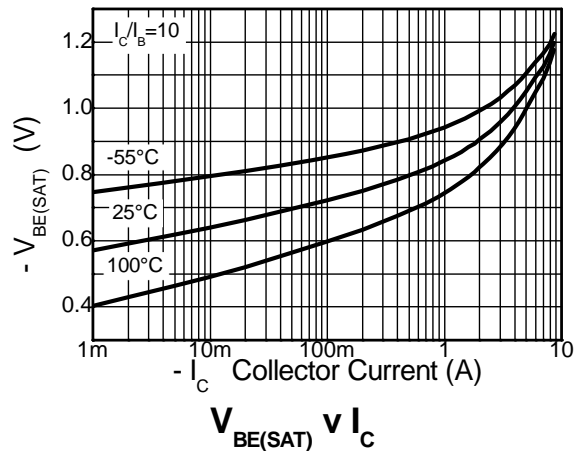
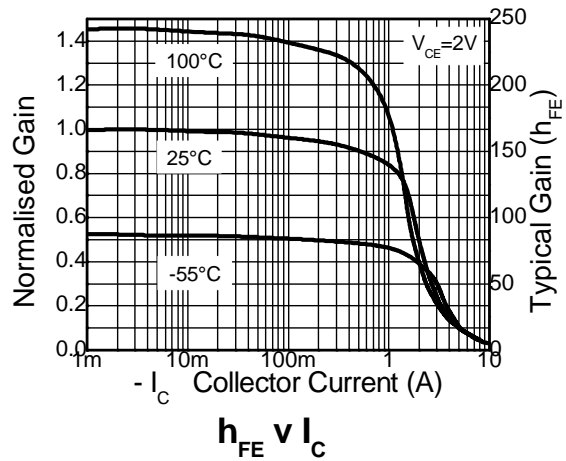
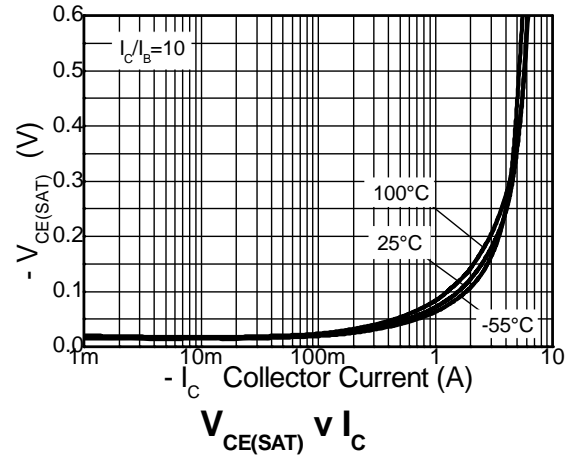
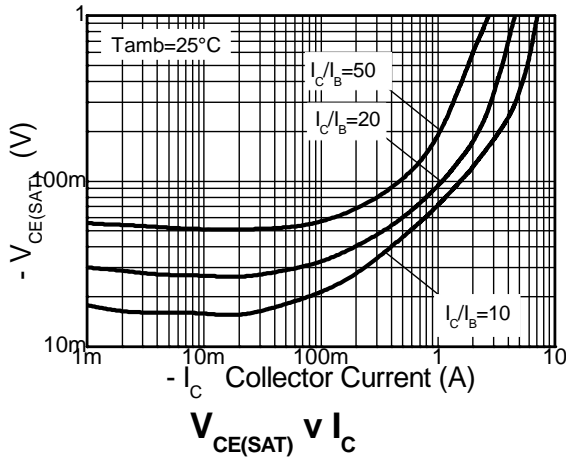
**Pulse Power Dissipation**

**Electrical Characteristics** @ $T_A = 25^\circ\text{C}$  unless otherwise specified

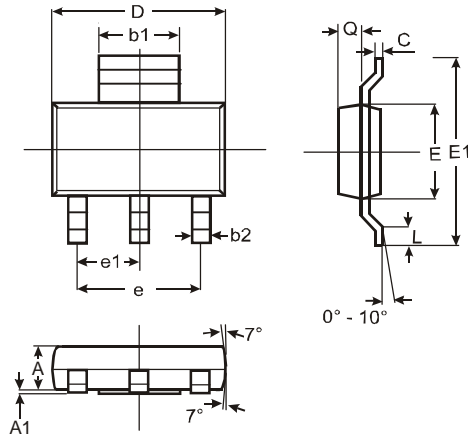
Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	$BV_{CBO}$	-140	-160	-	V	$I_C = -100\mu\text{A}$
Collector-Emitter Breakdown Voltage	$BV_{CER}$	-140	-160	-	V	$I_C = -1\mu\text{A}$ , $R_B \leq 1\text{k}\Omega$
Collector-Emitter Breakdown Voltage (Note 8)	$BV_{CEO}$	-100	-115	-	V	$I_C = -10\text{mA}$
Emitter-Base Breakdown Voltage	$BV_{EBO}$	-7	-8.1	-	V	$I_E = -100\mu\text{A}$
Collector-Base Cutoff Current	$I_{CBO}$	-	<1	-20	nA	$V_{CB} = -100\text{V}$
				-0.5	$\mu\text{A}$	$V_{CB} = -100\text{V}$ , $T_A = 100^\circ\text{C}$
Collector-Emitter Cutoff Current	$I_{CER}$ $R \leq 1\text{k}\Omega$	-	<1	-20	nA	$V_{CB} = -100\text{V}$
				-0.5	$\mu\text{A}$	$V_{CB} = -100\text{V}$ , $T_A = 100^\circ\text{C}$
Emitter Cutoff Current	$I_{EBO}$	-	<1	-10	nA	$V_{EB} = -6\text{V}$
Static Forward Current Transfer Ratio (Note 8)	$h_{FE}$	100	250	-	-	$I_C = -10\text{mA}$ , $V_{CE} = -1\text{V}$
		100	200	300		$I_C = -1\text{A}$ , $V_{CE} = -1\text{V}$
		25	50	-		$I_C = -3\text{A}$ , $V_{CE} = -1\text{V}$
		15	30	-		$I_C = -4\text{A}$ , $V_{CE} = -1\text{V}$
		-	5	-		$I_C = -10\text{A}$ , $V_{CE} = -1\text{V}$
Collector-Emitter Saturation Voltage (Note 8)	$V_{CE(sat)}$	-	-20	-30	mV	$I_C = -100\text{mA}$ , $I_B = -10\text{mA}$
		-	-70	-90		$I_C = -1\text{A}$ , $I_B = -100\text{mA}$
		-	-120	-150		$I_C = -2\text{A}$ , $I_B = -200\text{mA}$
		-	-240	-340		$I_C = -4\text{A}$ , $I_B = -400\text{mA}$
Base-Emitter Saturation Voltage (Note 8)	$V_{BE(sat)}$	-	-985	-1100	mV	$I_C = -4\text{A}$ , $I_B = -400\text{mA}$
Base-Emitter Turn-On Voltage (Note 8)	$V_{BE(on)}$	-	-920	-1050	mV	$I_C = -4\text{A}$ , $V_{CE} = -2\text{V}$
Output Capacitance (Note 8)	$C_{obo}$	-	42	-	pF	$V_{CB} = -10\text{V}$ , $f = 1\text{MHz}$
Transition Frequency	$f_T$	-	125	-	MHz	$V_{CE} = -10\text{V}$ , $I_C = -100\text{mA}$ $f = 50\text{MHz}$
Switching Time	$t_{on}$	-	42	-	ns	$V_{CC} = -10\text{V}$ , $I_C = -1\text{A}$ $I_{B1} = I_{B2} = -100\text{mA}$
	$t_{off}$	-	540	-		

Notes: 8. Measured under pulsed conditions. Pulse width  $\leq 300\mu\text{s}$ . Duty cycle  $\leq 2\%$

**Typical Electrical Characteristics**

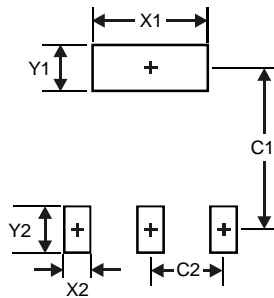


**Package Outline Dimensions**



SOT223			
Dim	Min	Max	Typ
A	1.55	1.65	1.60
A1	0.010	0.15	0.05
b1	2.90	3.10	3.00
b2	0.60	0.80	0.70
C	0.20	0.30	0.25
D	6.45	6.55	6.50
E	3.45	3.55	3.50
E1	6.90	7.10	7.00
e	—	—	4.60
e1	—	—	2.30
L	0.85	1.05	0.95
Q	0.84	0.94	0.89
All Dimensions in mm			

**Suggested Pad Layout**



Dimensions	Value (in mm)
X1	3.3
X2	1.2
Y1	1.6
Y2	1.6
C1	6.4
C2	2.3

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